

# Bidirectional Fault Protection and Detection, 10 $\Omega$ R<sub>ON</sub>, Quad SPST Switches

### **Data Sheet**

# ADG5412BF/ADG5413BF

#### FEATURES

Overvoltage protection up to -55 V and +55 V Power-off protection up to -55 V and +55 V Overvoltage detection on source and drain pins Low on resistance: 10 Ω On-resistance flatness of 0.5 Ω 3 kV human body model (HBM) ESD rating Latch-up immune under any circumstance Known state without digital inputs present V<sub>SS</sub> to V<sub>DD</sub> analog signal range ±5 V to ±22 V dual-supply operation 8 V to 44 V single-supply operation Fully specified at ±15 V, ±20 V, +12 V, and +36 V

#### **APPLICATIONS**

Analog input/output modules Process control/distributed control systems Data acquisition Instrumentation Avionics Automatic test equipment Communication systems Relay replacement



Figure 2. ADG5413BF

#### **GENERAL DESCRIPTION**

The ADG5412BF and ADG5413BF contain four independently controlled single-pole/single-throw (SPST) switches. The ADG5412BF has four switches that turn on with Logic 1 inputs. The ADG5413BF has two switches that turn on and two switches that turn off with Logic 1 inputs. Each switch conducts equally well in both directions when on, and each switch has an input signal range that extends to the supplies. The digital inputs are compatible with 3 V logic inputs over the full operating supply range.

When no power supplies are present, the switch remains in the off condition, and the switch inputs are high impedance. Under normal operating conditions, if the analog input signal levels on any switch pin exceed  $V_{DD}$  or  $V_{SS}$  by a threshold voltage,  $V_T$ , the switch turns off. Input signal levels up to +55 V and -55 V relative to ground are blocked, in both the powered and unpowered condition.

Rev. B Document Feedback Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners. The low on resistance of these switches, combined with onresistance flatness over a significant portion of the signal range make them an ideal solution for data acquisition and gain switching applications where excellent linearity and low distortion are critical.

#### **PRODUCT HIGHLIGHTS**

- 1. Switch pins are protected against voltages greater than the supply rails, up to -55 V and +55 V.
- 2. Switch pins are protected against voltages between −55 V and +55 V, in an unpowered state.
- 3. Overvoltage detection with digital output indicates operating state of switches.
- 4. Trench isolation guards against latch-up.
- 5. Optimized for low on resistance and on-resistance flatness.
- 6. The ADG5412BF/ADG5413BF can be operated from a dual-supply of ±5 V up to ±22 V or a single power supply of 8 V up to 44 V.

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#### 3/15—Rev. 0 to Rev. A

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7/14—Revision 0: Initial Version

## **SPECIFICATIONS**

#### ±15 V DUAL-SUPPLY

 $V_{\text{DD}}$  = 15 V  $\pm$  10%,  $V_{\text{SS}}$  = –15 V  $\pm$  10%, GND = 0 V,  $C_{\text{DECOUPLING}}$  = 0.1  $\mu\text{F},$  unless otherwise noted.

#### Table 1.

Parameter	+25°C	–40°C to +85°C	-40°C to +125°C	Unit	Test Conditions/Comments
ANALOG SWITCH				•	$V_{DD} = 13.5 \text{ V}, \text{ V}_{SS} = -13.5 \text{ V}, \text{ see Figure 32}$
Analog Signal Range			V <sub>DD</sub> to V <sub>SS</sub>	v	$v_{00} = 13.5 v, v_{33} = 13.5 v, see Figure 52$
On Resistance, $R_{ON}$	10		100 00 135	Ωtyp	$V_{s} = \pm 10 V$ , $I_{s} = -10 mA$
Of Resistance, non	11.2	14	16.5	$\Omega \max$	V3 - ±10 V, 15 - 10 IIIA
	9.5	17	10.5	Ωtyp	$V_{s} = \pm 9 V$ , $I_{s} = -10 mA$
	10.7	13.5	16	$\Omega \max$	$V_{5} = \pm 9 V, 15 = -10 \text{ IIIA}$
On-Resistance Match Between Channels, $\Delta R_{ON}$	0.05	15.5	10	Ω typ	$V_{s} = \pm 10 V_{s} I_{s} = -10 \text{ mA}$
OII-Resistance Match between Charmers, Aron	0.03	0.6	0.7	$\Omega \max$	$v_{s} = \pm 10 v, i_{s} = -10 \text{ IIIA}$
	0.05	0.0	0.7		$V_{s} = \pm 9 V_{s} I_{s} = -10 \text{ mA}$
	0.05	0.5	0.5	Ω typ Ω max	$V_{S} = \pm 9 V, I_{S} = -10 IIIA$
On Desistance Flate and D		0.5	0.5		
On-Resistance Flatness, R <sub>FLAT(ON)</sub>	0.6			Ω typ	$V_{s} = \pm 10 V$ , $I_{s} = -10 mA$
	0.9	1.1	1.1	Ωmax	
	0.1			Ω typ	$V_s = \pm 9 V$ , $I_s = -10 mA$
	0.4	0.5	0.5	Ωmax	
Threshold Voltage, V <sub>T</sub>	0.7			V typ	See Figure 28
LEAKAGE CURRENTS					$V_{DD} = 16.5 V, V_{SS} = -16.5 V$
Source Off Leakage, Is (Off)	±0.1			nA typ	$V_s = \pm 10 V$ , $V_D = \mp 10 V$ , see Figure 33
	±1.5	±5.5	±24	nA max	
Drain Off Leakage, $I_D$ (Off)	±0.1			nA typ	$V_s = \pm 10 V$ , $V_D = \mp 10 V$ , see Figure 33
	±1.5	±5.5	±20	nA max	
Channel On Leakage, I <sub>D</sub> (On), I <sub>s</sub> (On)	±0.3			nA typ	$V_s = V_D = \pm 10 V$ , see Figure 34
	±2.0	±2.5	±5.5	nA max	
FAULT					
Input Leakage Current, Is or ID					
With Overvoltage			±78	μA typ	$V_{DD} = 16.5 V, V_{SS} = 16.5 V, GND = 0 V, V_S$
2					or $V_D = \pm 55$ V, see Figure 37
Power Supplies Grounded or Floating			±40	μA typ	$V_{DD} = 0 V$ or floating, $V_{SS} = 0 V$ or floating, GND = 0 V, INx = 0 V or floating, V <sub>S</sub> or V <sub>D</sub> = ±55 V, see Figure 38
Output Leakage Current, Is or ID					
With Overvoltage	±20			nA typ	$V_{DD} = 16.5 \text{ V}, V_{SS} = 16.5 \text{ V}, \text{GND} = 0 \text{ V}, \text{V}_{S}$ or $V_{D} = \pm 55 \text{ V},$ see Figure 37
	±200	±250	±250	nA max	
Power Supplies Grounded	±10			nA typ	$V_{DD} = 0 V, V_{SS} = 0 V, GND = 0 V, V_S \text{ or } V_D = \pm 55 V, INx = 0 V, see Figure 38$
	±30	±50	±100	nA max	
Power Supplies Floating	±10	±10	±10	μA typ	$V_{DD} = floating, V_{SS} = floating, GND = 0 V, V_S \text{ or } V_D = \pm 55 V, INx = 0 V, see Figure 38$
DIGITAL INPUTS/OUTPUTS					
Input Voltage					
High, V <sub>INH</sub>			2.0	V min	
Low, V <sub>INL</sub>			0.8	V max	
Input Current, I <sub>INL</sub> or I <sub>INH</sub>	±0.7			μA typ	$V_{IN} = V_{GND} \text{ or } V_{DD}$
• • • • • • • • • • • • • • • • • • •			±1.2	µA max	
	5.0			pF typ	

Parameter	+25°C	–40°C to +85°C	-40°C to +125°C	Unit	Test Conditions/Comments
Output Voltage				V min	
High, V <sub>он</sub>	2.0			V min	
Low, V <sub>OL</sub>	0.8			V max	
DYNAMIC CHARACTERISTICS <sup>1</sup>					
t <sub>on</sub>	400			ns typ	$R_L = 300 \Omega, C_L = 35 pF$
	495	525	550	ns max	Vs = 10 V, see Figure 47
t <sub>OFF</sub>	410			ns typ	$R_L = 300 \Omega$ , $C_L = 35 pF$
	510	545	555	ns max	Vs = 10 V, see Figure 47
Break-Before-Make Time Delay, t <sub>D</sub> (ADG5413BF Only)	285			ns typ	$R_L = 300 \ \Omega, \ C_L = 35 \ pF$
			185	ns min	$V_{s1} = V_{s2} = 10 V$ , see Figure 46
Overvoltage Response Time, t <sub>RESPONSE</sub>	460			ns typ	$R_L = 1 \text{ k}\Omega$ , $C_L = 2 \text{ pF}$ , see Figure 41
	585	615	630	ns max	
Overvoltage Recovery Time, t <sub>RECOVERY</sub>	720			ns typ	$R_L = 1 \text{ k}\Omega$ , $C_L = 2 \text{ pF}$ , see Figure 42
	930	1050	1100	ns max	
Interrupt Flag Response Time, tDIGRESP	85		115	ns typ	$C_L = 10 \text{ pF}$ , see Figure 43
Interrupt Flag Recovery Time, tDIGREC	60		85	µs typ	$C_L = 10 \text{ pF}$ , see Figure 44
	600			ns typ	$C_L = 10 \text{ pF, } R_{PULLUP} = 1 \text{ k}\Omega, \text{ see}$ Figure 45
Charge Injection, Q <sub>INJ</sub>	-680			pC typ	$V_s = 0 V$ , $R_s = 0 \Omega$ , $C_L = 1 nF$ , see Figure 4
Off Isolation	-70			dB typ	$R_L$ = 50 $\Omega,$ $C_L$ = 5 pF, f = 1 MHz, see Figure 35
Channel-to-Channel Crosstalk	-90			dB typ	$R_L$ = 50 $\Omega,C_L$ = 5 pF, f = 1 MHz, see Figure 36
Total Harmonic Distortion Plus Noise, THD + N	0.0015			% typ	$R_L = 10 \text{ k}\Omega, V_S = 15 \text{ V p-p}, f = 20 \text{ Hz to}$ 20 kHz, see Figure 40
–3 dB Bandwidth	270			MHz typ	$R_L = 50 \Omega$ , $C_L = 5 pF$ , see Figure 39
Insertion Loss	-0.72			dB typ	$R_L = 50 \Omega$ , $C_L = 5 pF$ , $f = 1 MHz$ , see Figure 39
C <sub>s</sub> (Off)	13			pF typ	$V_s = 0 V, f = 1 MHz$
C <sub>D</sub> (Off)	12			pF typ	$V_s = 0 V$ , $f = 1 MHz$
C <sub>D</sub> (On), C <sub>s</sub> (On)	24			pF typ	$V_s = 0 V, f = 1 MHz$
POWER REQUIREMENTS					$V_{DD} = 16.5 V$ , $V_{SS} = -16.5 V$ , digital inputs 0 V, 5 V, or $V_{DD}$
Normal Mode					
DD	0.9			mA typ	
	1.2		1.3	mA max	
Ignd	0.4			mA typ	
	0.55		0.6	mA max	
lss	0.5			mA typ	
	0.65		0.7	μA max	
Fault Mode					$V_s = \pm 55 V$
DD	1.2			mA typ	
	1.6		1.8	mA max	
I <sub>GND</sub>	0.8			mA typ	
	1.0		1.1	mA max	
I <sub>ss</sub>	0.5			mA typ	
	1.0		1.8	mA max	
V <sub>DD</sub> /V <sub>SS</sub>			±5	V min	GND = 0 V
			±22	V max	GND = 0 V

<sup>1</sup> Guaranteed by design; not subject to production test.

#### ±20 V DUAL-SUPPLY

 $V_{\text{DD}}$  = 20 V  $\pm$  10%,  $V_{\text{SS}}$  = –20 V  $\pm$  10%, GND = 0 V,  $C_{\text{DECOUPLING}}$  = 0.1  $\mu\text{F}$  unless otherwise noted.

#### Table 2.

Parameter	+25°C	-40°C to +85°C	-40°C to +125°C	Unit	Test Conditions/Comments
ANALOG SWITCH					$V_{DD} = 18 V, V_{SS} = -18 V, see$ Figure 32
Analog Signal Range			V <sub>DD</sub> to V <sub>SS</sub>	V	ligare 32
On Resistance, R <sub>ON</sub>	10		• • • • • • • • • • • • •	Ω typ	$V_{s} = \pm 15 V$ , $I_{s} = -10 mA$
	11.5	14.5	16.5	Ωmax	
	9.5			Ωtyp	$V_s = \pm 13.5 V$ , $I_s = -10 mA$
	11	14	16.5	Ωmax	
On-Resistance Match Between Channels, $\Delta R_{ON}$	0.05			Ωtyp	$V_{s} = \pm 15 V$ , $I_{s} = -10 mA$
	0.35	0.5	0.5	Ωmax	
	0.05			Ωtyp	$V_s = \pm 13.5 V$ , $I_s = -10 mA$
	0.35	0.5	0.5	Ωmax	
On-Resistance Flatness, R <sub>FLAT(ON)</sub>	1.0			Ωtyp	$V_{s} = \pm 15 V$ , $I_{s} = -10 mA$
	1.4	1.5	1.5	Ωmax	
	0.1			Ωtyp	$V_s = \pm 13.5 V$ , $I_s = -10 mA$
	0.4	0.5	0.5	Ωmax	
Threshold Voltage, V⊤	0.7			V typ	See Figure 28
LEAKAGE CURRENTS					$V_{DD} = 22 V, V_{SS} = -22 V$
Source Off Leakage, I <sub>s</sub> (Off)	±0.1			nA typ	$V_{s} = \pm 15 V, V_{D} = \mp 15 V, see Figure 33$
	±1.5	±5.5	±24	nA max	······································
Drain Off Leakage, $I_D$ (Off)	±0.1	±3.5	<u> </u>	nA typ	$V_s = \pm 15 V$ , $V_D = \mp 15 V$ , see Figure 33
	±1.5	±5.5	±20	nA max	v <sub>3</sub> =±13 v, v <sub>0</sub> = +13 v, see figure 33
Channel On Leakage, I <sub>D</sub> (On), I <sub>S</sub> (On)	±0.3	±3.5	-20	nA typ	$V_s = V_D = \pm 15 V$ , see Figure 34
Charmer on Leakage, 10 (On), is (On)	±0.5 ±2.0	±2.5	±5.5	nA max	$v_{s} = v_{0} = \pm 15$ v, see figure 54
FAULT					
Input Leakage Current, Is or ID					
With Overvoltage			±78	µA typ	$V_{DD} = 22 V, V_{SS} = -22 V, GND = 0 V,$ V <sub>S</sub> or V <sub>D</sub> = ±55 V, see Figure 37
Power Supplies Grounded or Floating			±40	µА tур	$\label{eq:VDD} \begin{array}{l} V_{DD} = 0 \ V \ or \ floating, \ V_{SS} = 0 \ V \ or \\ floating, \ GND = 0 \ V, \ INx = 0 \ V \ or \\ floating, \ V_S \ or \ V_D = \pm 55 \ V, \ see \\ Figure \ 38 \end{array}$
Output Leakage Current, Is or ID					
With Overvoltage	±0.4			μA typ	$V_{DD} = +22 V$ , $V_{SS} = -22 V$ , $GND = 0 V$ , $V_{S}$ or $V_{D} = \pm 55 V$ , see Figure 37
	±1.0	±1.0	±1.0	μA max	
Power Supplies Grounded	±10			nA typ	$V_{DD} = 0 V, V_{SS} = 0 V, GND = 0 V, V_S or$ $V_D = \pm 55 V, INx = 0 V, see Figure 38$
	±30	±50	±100	nA max	
Power Supplies Floating	±10	±10	±10	µA typ	$V_{DD}$ = floating, $V_{SS}$ = floating, GND = 0 V, V <sub>S</sub> or V <sub>D</sub> = ±55 V, INx = 0 V,
					see Figure 38
DIGITAL INPUTS					
Input Voltage			20	Vmin	
High, V <sub>INH</sub>			2.0	V min	
Low, V <sub>INL</sub>	07		0.8	V max	
Input Current, I <sub>INL</sub> or I <sub>INH</sub>	0.7		1.2	μA typ	$V_{IN} = V_{GND} \text{ or } V_{DD}$
Disitella set Care site	5.0		1.2	μA max	
Digital Input Capacitance, C <sub>IN</sub>	5.0			pF typ	

Parameter	+25°C	-40°C to +85°C	–40°C to +125°C	Unit	Test Conditions/Comments
Output Voltage					
High, V <sub>он</sub>	2.0			V min	
Low, V <sub>OL</sub>	0.8			V max	
DYNAMIC CHARACTERISTICS <sup>1</sup>					
t <sub>on</sub>	400			ns typ	$R_L = 300 \Omega$ , $C_L = 35 pF$
	500	530	555	ns max	$V_s = 10 V$ , see Figure 47
t <sub>OFF</sub>	415			ns typ	$R_L = 300 \Omega, C_L = 35 pF$
	515	550	565	ns max	Vs = 10 V, see Figure 47
Break-Before-Make Time Delay, t <sub>D</sub> (ADG5413BF Only)	295			ns typ	$R_L = 300 \ \Omega, \ C_L = 35 \ pF$
			200	ns min	$V_{s1} = V_{s2} = 10 V$ , see Figure 46
Overvoltage Response Time, t <sub>RESPONSE</sub>	370			ns typ	$R_L = 1 \text{ k}\Omega$ , $C_L = 2 \text{ pF}$ , see Figure 41
	480	500	515	ns max	
Overvoltage Recovery Time, t <sub>RECOVERY</sub>	840			ns typ	$R_L = 1 \text{ k}\Omega$ , $C_L = 2 \text{ pF}$ , see Figure 42
	1200	1400	1700	ns max	
Interrupt Flag Response Time, tDIGRESP	85		115	ns typ	$C_L = 10 \text{ pF}$ , see Figure 43
Interrupt Flag Recovery Time, tDIGREC	60		85	μs typ	$C_L = 10 \text{ pF}$ , see Figure 44
	600			ns typ	$C_L = 10 \text{ pF}, R_{PULLUP} = 1 \text{ k}\Omega, \text{ see}$ Figure 45
Charge Injection, Q <sub>INJ</sub>	-640			pC typ	$V_s = 0 V$ , $R_s = 0 \Omega$ , $C_L = 1 nF$ , see Figure 48
Off Isolation	-70			dB typ	$R_L = 50 \Omega$ , $C_L = 5 pF$ , $f = 1 MHz$ , see Figure 35
Channel-to-Channel Crosstalk	-90			dB typ	$R_L = 50 \Omega$ , $C_L = 5 pF$ , $f = 1 MHz$ , see Figure 36
Total Harmonic Distortion Plus Noise, THD + N	0.001			% typ	$\begin{array}{l} R_{\text{L}}=10 \; k\Omega, V_{\text{S}}=20 \; V \; p\text{-}p,  f=20 \; \text{Hz} \\ \text{to } 20 \; \text{kHz},  \text{see Figure 40} \end{array}$
–3 dB Bandwidth	270			MHz typ	$R_L = 50 \Omega$ , $C_L = 5 pF$ , see Figure 39
Insertion Loss	-0.73			dB typ	$R_L = 50 \Omega$ , $C_L = 5 pF$ , $f = 1 MHz$ , see Figure 39
C <sub>s</sub> (Off)	12			pF typ	$V_{s} = 0 V, f = 1 MHz$
C <sub>D</sub> (Off)	11			pF typ	$V_{s} = 0 V, f = 1 MHz$
C <sub>D</sub> (On), C <sub>S</sub> (On)	23			pF typ	$V_{s} = 0 V, f = 1 MHz$
POWER REQUIREMENTS					$V_{DD} = 22 V$ , $V_{SS} = -22 V$ , digital inputs = 0 V, 5 V, or $V_{DD}$
Normal Mode					
I <sub>DD</sub>	0.9			mA typ	
	1.2		1.3	mA max	
Ignd	0.4			mA typ	
	0.55		0.6	mA max	
lss	0.5			mA typ	
	0.65		0.7	mA max	
Fault Mode					$V_s = \pm 55 V$
ldd	1.2			mA typ	
	1.6		1.8	mA max	
Ignd	0.8			mA typ	
	1.0		1.1	mA max	
lss	0.5			mA typ	
	1.0		1.8	mA max	
V <sub>DD</sub> /V <sub>SS</sub>			±5	V min	GND = 0 V
			±22	V max	GND = 0 V

<sup>1</sup> Guaranteed by design; not subject to production test.

#### **12 V SINGLE-SUPPLY**

 $V_{\text{DD}}$  = 12 V  $\pm$  10%,  $V_{\text{SS}}$  = 0 V, GND = 0 V,  $C_{\text{DECOUPLING}}$  = 0.1  $\mu\text{F}$  unless otherwise noted.

#### Table 3.

+25°C	-40°C to +85°C	-40°C to +125°C	Unit	Test Conditions/Comments
1	1	1	1	$V_{DD} = 10.8 V, V_{SS} = 0 V$ , see Figure 32
		0 V to V <sub>DD</sub>	V	
22			Ωtyp	$V_s = 0 V$ to 10 V, $I_s = -10 mA$
24.5	31	37	Ωmax	
10			Ωtyp	$V_s = 3.5 V$ to 8.5 V, $I_s = -10 \text{ mA}$
11.2	14	16.5	Ωmax	
0.05			Ωtyp	$V_s = 0 V$ to 10 V, $I_s = -10 mA$
0.5	0.6	0.7	Ωmax	
0.05			Ωtyp	$V_s = 3.5 V$ to 8.5 V, $I_s = -10 \text{ mA}$
0.5	0.6	0.7	Ω max	
12.5			Ωtyp	$V_s = 0 V$ to 10 V, $I_s = -10 mA$
14.5	19	23	Ωmax	
0.6			Ωtyp	$V_s = 3.5 V$ to 8.5 V, $I_s = -10 \text{ mA}$
0.9	1.1	1.3	Ω max	
0.7			V typ	See Figure 28
				$V_{DD} = 13.2 \text{ V}, V_{SS} = 0 \text{ V}$
±0.1			nA typ	$V_{\rm S}$ = 1 V/10 V, $V_{\rm D}$ = 10 V/1 V, see Figure 33
±1.5	±5.5	±24	nA max	
±0.1			nA typ	$V_s = 1 \text{ V}/10 \text{ V}$ , $V_D = 10 \text{ V}/1 \text{ V}$ , see Figure 33
±1.5	±5.5	±20	nA max	
±0.3			nA typ	$V_s = V_D = 1 \text{ V}/10 \text{ V}$ , see Figure 34
±2.0	±2.5	±5.5	nA max	
		±78	μA typ	$V_{DD} = 13.2 \text{ V}, V_{SS} = 0 \text{ V}, \text{ GND} = 0 \text{ V}, \text{ V}_{S} \text{ or}$ $V_{D} = \pm 55 \text{ V}, \text{ see Figure 37}$
		±40	μA typ	$V_{DD} = 0$ V or floating, $V_{SS} = 0$ V or floating, GND = 0 V, INx = 0 V or floating, $V_S$ or $V_D = \pm 55$ V, see Figure 38
±20			nA typ	$V_{DD} = 13.2 \text{ V}, V_{SS} = 0 \text{ V}, \text{ GND} = 0 \text{ V}, \text{ V}_{S} \text{ or}$ $V_{D} = \pm 55 \text{ V}, \text{ see Figure 37}$
±200	±250	±250	nA max	
±10			nA typ	$V_{DD} = 0 V$ , $V_{SS} = 0 V$ , $GND = 0 V$ , $V_S$ or $V_D = \pm 55 V$ , $INx = 0 V$ , see Figure 38
±30	±50	±100	nA max	
±10	±10	±10	μA typ	$V_{DD} = floating, V_{SS} = floating, GND = 0 V, V_S \text{ or } V_D = \pm 55 V, INx = 0 V, see Figure 38$
		2.0	V min	
		0.8	V max	
0.7			μA typ	$V_{IN} = V_{GND} \text{ or } V_{DD}$
		1.2	µA max	
1	1	1		
5.0			pF typ	
5.0 2.0			рг typ V min	
	22 24.5 10 11.2 0.05 0.5 12.5 14.5 0.6 0.9 0.7 $\pm 0.1$ $\pm 1.5$ $\pm 0.1$ $\pm 1.5$ $\pm 0.1$ $\pm 1.5$ $\pm 0.3$ $\pm 2.0$ $\pm 2.0$ $\pm 10$ $\pm 10$	$\begin{array}{cccccccccccccccccccccccccccccccccccc$	+25°C +85°C +125°C   22 31 0 V to VDD   24.5 31 37   10 14 16.5   11.2 14 0.7   0.5 0.6 0.7   0.5 0.6 0.7   0.5 0.6 0.7   0.5 1.1 1.3   0.6 1.1 1.3   0.7 1.3 1.4   1.5 ±5.5 ±24   ±0.1 ±5.5 ±20   ±0.1 ±5.5 ±20   ±0.3 ±2.0 ±5.5   ±0.3 ±2.5 ±5.5   ±2.0 ±2.5 ±40   ±2.0 ±2.5 ±10   ±200 ±250 ±250   ±30 ±50 ±100   ±10 ±10 ±10	+25°C+85°C+125°CUnit22 $0 \vee to \vee V_{DD}$ $V$ 24.531 $37$ $\Omega \max$ 1014 $16.5$ $\Omega \max$ 0.050.6 $0.7$ $\Omega \max$ 0.50.6 $0.7$ $\Omega \max$ 0.50.6 $0.7$ $\Omega \max$ 0.50.6 $0.7$ $\Omega \max$ 0.6 $0.7$ $\Omega \max$ 0.6 $0.7$ $\Omega \max$ 0.71.1 $1.3$ $\Omega \max$ 0.6 $23$ $\Omega \max$ 0.7 $23$ $\Omega \max$ $0.7$ $1.1$ $1.3$ $\Omega \max$ $0.7$ $\pm 5.5$ $\pm 24$ $nA typ$ $\pm 1.5$ $\pm 5.5$ $\pm 20$ $nA max$ $0.1$ $\pm 5.5$ $\pm 20$ $nA max$ $1.1$ $\pm 1.5$ $\pm 2.0$ $\mu x$ $\pm 0.1$ $\pm 5.5$ $\pm 78$ $\mu A$ $\pm 10$ $\pm 250$ $\pm 78$ $\mu A$ $\pm 200$ $\pm 250$ $\pm 250$ $nA max$ $\pm 10$ $\pm 10$ $\mu x$ $\mu x$ $\pm 10$ $\pm 50$ $\pm 100$ $nA max$ $\pm 10$ $\pm 10$ $\mu x$

Parameter	+25°C	–40°C to +85°C	-40°C to +125°C	Unit	Test Conditions/Comments
DYNAMIC CHARACTERISTICS <sup>1</sup>					
ton	400			ns typ	$R_L = 300 \Omega$ , $C_L = 35 pF$
	485	515	540	ns max	Vs = 8 V, see Figure 47
toff	375			ns typ	$R_L = 300 \ \Omega$ , $C_L = 35 \ pF$
	460	495	520	ns max	V <sub>s</sub> = 8 V, see Figure 47
Break-Before-Make Time Delay, t <sub>D</sub> (ADG5413BF Only)	260			ns typ	$R_L = 300 \ \Omega, C_L = 35 \ pF$
			170	ns min	$V_{S1} = V_{S2} = 8 V$ , see Figure 46
Overvoltage Response Time, tresponse	560			ns typ	$R_L = 1 \text{ k}\Omega$ , $C_L = 2 \text{ pF}$ , see Figure 41
	660	700	720	ns max	
Overvoltage Recovery Time, t <sub>RECOVERY</sub>	640			ns typ	$R_L = 1 \text{ k}\Omega$ , $C_L = 2 \text{ pF}$ , see Figure 42
	800	865	960	ns max	
Interrupt Flag Response Time, t <sub>DIGRESP</sub>	85		115	ns typ	$C_L = 10 \text{ pF}$ , see Figure 43
Interrupt Flag Recovery Time, tDIGREC	60		85	µs typ	$C_L = 10 \text{ pF}$ , see Figure 44
	600			ns typ	$C_L = 10 \text{ pF}, R_{PULLUP} = 1 \text{ k}\Omega$ , see Figure 45
Charge Injection, Q <sub>INJ</sub>	-340			pC typ	$V_s = 6 V$ , $R_s = 0 \Omega$ , $C_L = 1 nF$ , see Figure 4
Off Isolation	-65			dB typ	$R_L = 50 \Omega$ , $C_L = 5 pF$ , $f = 1 MHz$ , see Figure 35
Channel-to-Channel Crosstalk	-90			dB typ	$R_L = 50 \Omega$ , $C_L = 5 pF$ , $f = 1 MHz$ , see Figure 36
Total Harmonic Distortion Plus Noise, THD + N	0.007			% typ	$R_L = 10 \text{ k}\Omega$ , $V_S = 6 \text{ V p-p}$ , $f = 20 \text{ Hz to}$ 20 kHz, see Figure 40
–3 dB Bandwidth	270			MHz typ	$R_L = 50 \Omega$ , $C_L = 5 pF$ , see Figure 39
Insertion Loss	-0.74			dB typ	$R_L$ = 50 $\Omega,$ $C_L$ = 5 pF, $f$ = 1 MHz, see Figure 39
C <sub>s</sub> (Off)	16			pF typ	$V_{s} = 6 V, f = 1 MHz$
C <sub>D</sub> (Off)	15			pF typ	$V_{s} = 6 V, f = 1 MHz$
C <sub>D</sub> (On), C <sub>s</sub> (On)	25			pF typ	$V_{s} = 6 V, f = 1 MHz$
POWER REQUIREMENTS					$V_{\text{DD}}$ = 13.2 V, $V_{\text{SS}}$ = 0 V, digital inputs = 0 5 V, or $V_{\text{DD}}$
Normal Mode					
I <sub>DD</sub>	0.9			mA typ	
	1.2		1.3	mA max	
I <sub>GND</sub>	0.4			mA typ	
	0.55		0.6	mA max	
lss	0.5			mA typ	
	0.65		0.7	mA max	
Fault Mode					$V_s = \pm 55 V$
l <sub>DD</sub>	1.2			mA typ	
	1.6		1.8	mA max	
I <sub>GND</sub>	0.8			mA typ	
	1.0		1.1	mA max	
lss	0.5			mA typ	
	1.0		1.8	mA max	
V <sub>DD</sub>			8	V min	$V_{SS} = GND = 0 V$
			44	V max	$V_{SS} = GND = 0 V$

<sup>1</sup> Guaranteed by design; not subject to production test.

#### **36 V SINGLE-SUPPLY**

 $V_{\text{DD}}$  = 36 V  $\pm$  10%,  $V_{\text{SS}}$  = 0 V, GND = 0 V,  $C_{\text{DECOUPLING}}$  = 0.1  $\mu\text{F}$  unless otherwise noted.

#### Table 4.

Parameter	+25°C	-40°C to +85°C	-40°C to +125°C	Unit	Test Conditions/Comments
ANALOG SWITCH					$V_{DD} = 32.4 V, V_{SS} = 0 V$ , see Figure 32
Analog Signal Range			$0 V$ to $V_{DD}$	V	
On Resistance, R <sub>on</sub>	22			Ωtyp	$V_s = 0 V$ to 30 V, $I_s = -10 mA$
	24.5	31	37	Ωmax	
	10			Ωtyp	$V_s = 4.5 V$ to 28 V, $I_s = -10 mA$
	11	14	16.5	Ωmax	
On-Resistance Match Between Channels, $\Delta R_{ON}$	0.05			Ω typ	$V_{s} = 0 V$ to 30 V, $I_{s} = -10 mA$
	0.5	0.6	0.7	Ωmax	
	0.05			Ω typ	$V_s = 4.5 V$ to 28 V, $I_s = -10 mA$
	0.35	0.5	0.5	Ωmax	
On-Resistance Flatness, R <sub>FLAT(ON)</sub>	12.5			Ω typ	$V_{s} = 0 V$ to 30 V, $I_{s} = -10 mA$
	14.5	19	23	Ωmax	
	0.1			Ωtyp	$V_{s} = 4.5 V$ to 28 V, $I_{s} = -10 \text{ mA}$
	0.4	0.5	0.5	Ωmax	
Threshold Voltage, V⊤	0.7			V typ	See Figure 28
LEAKAGE CURRENTS					$V_{DD} = 39.6 \text{ V}, \text{ V}_{SS} = 0 \text{ V}$
Source Off Leakage, $I_s$ (Off)	±0.1			nA typ	$V_s = 1 \text{ V}/30 \text{ V}, V_D = 30 \text{ V}/1 \text{ V}, \text{ see}$ Figure 33
	±1.5	±5.5	±24	nA max	
Drain Off Leakage, $I_D$ (Off)	±0.1			nA typ	$V_s = 1 \text{ V}/30 \text{ V}, V_D = 30 \text{ V}/1 \text{ V}, \text{ see}$ Figure 33
	±1.5	±5.5	±20	nA max	_
Channel On Leakage, I <sub>D</sub> (On), Is (On)	±0.3			nA typ	$V_S = V_D = 1 \text{ V}/30 \text{ V}$ , see Figure 34
	±2.0	±2.5	±5.5	nA max	_
FAULT					
Input Leakage Current, $I_S$ or $I_D$					
With Overvoltage			±78	µА tур	$V_{DD} = 39.6 V, V_{SS} = 0 V, GND = 0 V, V_S o$ $V_D = +55 V, -40 V$ , see Figure 37
Power Supplies Grounded or Floating			±40	μА typ	$\label{eq:VDD} \begin{array}{l} V_{DD} = 0 \ V \ or \ floating, V_{SS} = 0 \ V \ or \\ floating, GND = 0 \ V, INx = 0 \ V \ or \\ floating, V_S \ or \ V_D = \pm 55 \ V, see \ Figure \ 38 \end{array}$
Output Leakage Current, $I_S$ or $I_D$					
With Overvoltage	±20			nA typ	$V_{DD} = 39.6 V$ , $V_{SS} = 0 V$ , $GND = 0 V$ , $V_S$ or $V_D = +55 V$ , $-40 V$ , see Figure 37
	±200	±250	±250	nA max	
Power Supplies Grounded	±10			nA typ	$V_{DD} = 0 V, V_{SS} = 0 V, GND = 0 V, V_s or$ $V_D = \pm 55 V, INx = 0 V, see Figure 38$
	±30	±50	±100	nA max	
Power Supplies Floating	±10	±10	±10	μA typ	$V_{DD}$ = floating, $V_{SS}$ = floating, GND = 0 V, $V_S$ or $V_D$ = ±55 V, INx = 0 V, see Figure 38
DIGITAL INPUTS	1			1	-
Input Voltage					
High, V <sub>INH</sub>			2.0	V min	
Low, V <sub>INL</sub>			0.8	V max	
	0.7			μA typ	$V_{IN} = V_{GND} \text{ or } V_{DD}$
1			1.2	μA max	
Digital Input Capacitance, C <sub>IN</sub>	5.0			pF typ	

Parameter	+25°C	-40°C to +85°C	-40°C to +125°C	Unit	Test Conditions/Comments
Output Voltage					
High, V <sub>он</sub>	2.0			V min	
Low, V <sub>OL</sub>	0.8			V max	
DYNAMIC CHARACTERISTICS <sup>1</sup>					
t <sub>on</sub>	400			ns typ	$R_L = 300 \Omega, C_L = 35 pF$
	490	520	545	ns max	Vs = 18 V, see Figure 47
t <sub>OFF</sub>	375			ns typ	$R_L = 300 \ \Omega$ , $C_L = 35 \ pF$
	460	485	510	ns max	Vs = 18 V, see Figure 47
Break-Before-Make Time Delay, t <sub>D</sub> (ADG5413BF Only)	285			ns typ	$R_L = 300 \ \Omega, \ C_L = 35 \ pF$
			195	ns min	$V_{S1} = V_{S2} = 18 V$ , see Figure 46
Overvoltage Response Time, t <sub>RESPONSE</sub>	250			ns typ	$R_L = 1 \text{ k}\Omega$ , $C_L = 2 \text{ pF}$ , see Figure 41
	350	360	375	ns max	
Overvoltage Recovery Time, t <sub>RECOVERY</sub>	1500			ns typ	$R_L = 1 \text{ k}\Omega$ , $C_L = 2 \text{ pF}$ , see Figure 42
	2000	2300	2700	ns max	
Interrupt Flag Response Time, t <sub>DIGRESP</sub>	85		115	ns typ	$C_L = 10 \text{ pF}$ , see Figure 43
Interrupt Flag Recovery Time, tDIGREC	60		85	µs typ	$C_L = 10 \text{ pF}$ , see Figure 44
	600			ns typ	$C_L = 10 \text{ pF}, R_{PULLUP} = 1 \text{ k}\Omega$ , see Figure 45
Charge Injection, Q <sub>INJ</sub>	-610			pC typ	$V_s = 18 V$ , $R_s = 0 \Omega$ , $C_L = 1 nF$ , see Figure 48
Off Isolation	-70			dB typ	$R_L = 50 \Omega$ , $C_L = 5 pF$ , $f = 1 MHz$ , see Figure 35
Channel-to-Channel Crosstalk	-90			dB typ	$R_L$ = 50 $\Omega,$ $C_L$ = 5 pF, f = 1 MHz, see Figure 36
Total Harmonic Distortion Plus Noise, THD + N	0.001			% typ	$\label{eq:RL} \begin{split} R_L &= 10 \; k\Omega, V_S = 18 \; V \; p\text{-}p,  f = 20 \; Hz \; to \\ 20 \; kHz,  see \; Figure \; 40 \end{split}$
–3 dB Bandwidth	270			MHz typ	$R_L = 50 \Omega$ , $C_L = 5 pF$ , see Figure 39
Insertion Loss	-0.75			dB typ	$R_L$ = 50 $\Omega,C_L$ = 5 pF, f = 1 MHz, see Figure 39
C <sub>s</sub> (Off)	12			pF typ	$V_s = 18 V, f = 1 MHz$
$C_{D}$ (Off)	11			pF typ	$V_s = 18 V, f = 1 MHz$
C <sub>D</sub> (On), C <sub>s</sub> (On)	23			pF typ	$V_s = 18 V, f = 1 MHz$
POWER REQUIREMENTS					$\label{eq:VDD} \begin{array}{l} V_{\text{DD}} = 39.6 \text{ V}, V_{\text{SS}} = 0 \text{ V}, \text{ digital inputs} = \\ 0 \text{ V}, 5 \text{ V}, \text{ or } V_{\text{DD}} \end{array}$
Normal Mode					
lod	0.9			mA typ	
	1.2		1.3	mA max	
Ignd	0.4			mA typ	
	0.55		0.6	mA max	
lss	0.5			mA typ	
	0.65		0.7	mA max	
Isolation Mode					$V_s = +55 V, -40 V$
l <sub>DD</sub>	1.2			mA typ	
	1.6		1.8	mA max	
I <sub>GND</sub>	0.8			mA typ	
	1.0		1.1	mA max	
I <sub>ss</sub>	0.5			mA typ	
	1.0		1.8	mA max	
V <sub>DD</sub>			8	V min	$V_{SS} = GND = 0 V$
			44	V max	$V_{SS} = GND = 0V$

<sup>1</sup> Guaranteed by design; not subject to production test.

#### CONTINUOUS CURRENT PER CHANNEL, Sx OR Dx

Table 5.					
Parameter	25°C	85°C	125°C	Unit	Test Conditions/Comments
16-LEAD TSSOP					
$\theta_{JA} = 112.6^{\circ}C/W$	83	59	39	mA max	$V_{S} = V_{SS} + 4.5 V$ to $V_{DD} - 4.5 V$
	64	48	29	mA max	$V_{S} = V_{SS} \text{ to } V_{DD}$
16-LEAD LFCSP					
$\theta_{JA} = 30.4^{\circ}C/W$	152	99	61	mA max	$V_{\text{S}} = V_{\text{SS}} + 4.5 \text{ V to } V_{\text{DD}} - 4.5 \text{ V}$
	118	80	52	mA max	$V_{S} = V_{SS} \text{ to } V_{DD}$

## **ABSOLUTE MAXIMUM RATINGS**

 $T_A = 25^{\circ}C$ , unless otherwise noted.

#### Table 6.

Parameter	Rating
V <sub>DD</sub> to V <sub>SS</sub>	48 V
V <sub>DD</sub> to GND	–0.3 V to +48 V
Vss to GND	-48 V to +0.3 V
Sx and Dx	–55 V to +55 V
Sx to V <sub>DD</sub> or V <sub>SS</sub>	80 V
Vs to VD	80 V
Digital Inputs	GND – 0.7 V to +48 V or 30 mA, whichever occurs first
Peak Current, Sx or Dx Pins	288 mA (pulsed at 1 ms, 10% duty cycle maximum)
Continuous Current, Sx or Dx Pins	Data <sup>1</sup> + 15%
Digital Output	GND – 0.7 V to 6 V or 30 mA, whichever occurs first
Operating Temperature Range	–40°C to +125°C
Storage Temperature Range	–65°C to +150°C
Junction Temperature	150°C
Thermal Impedance, θ <sub>JA</sub> (4-Layer Board)	
16-Lead TTSOP	112.6°C/W
16-Lead LFSCP	30.4°C/W
Reflow Soldering Peak Temperature, Pb Free	As per JEDEC J-STD-020
ESD (HBM: ANSI/ESD STM5.1-2007)	
I/O Port to Supplies	5.5 kV
I/O Port to I/O Port	5.5 kV
All Other Pins	3 kV

<sup>1</sup> See Table 5.

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

Only one absolute maximum rating can be applied at any one time.

#### **ESD CAUTION**



**ESD** (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

## **PIN CONFIGURATION AND FUNCTION DESCRIPTIONS**



#### **Table 7. Pin Function Descriptions**

Pin No.			
TSSOP	LFCSP	Mnemonic	Description
1	15	IN1	Logic Control Input.
2	16	D1	Overvoltage Protected Drain Terminal. This pin can be an input or an output.
3	1	S1	Overvoltage Protected Source Terminal. This pin can be an input or an output.
4	2	Vss	Most Negative Power Supply Potential.
5	3	GND	Ground (0 V) Reference.
6	4	S4	Overvoltage Protected Source Terminal. This pin can be an input or an output.
7	5	D4	Overvoltage Protected Drain Terminal. This pin can be an input or an output.
8	6	IN4	Logic Control Input.
9	7	IN3	Logic Control Input.
10	8	D3	Overvoltage Protected Drain Terminal. This pin can be an input or an output.
11	9	S3	Overvoltage Protected Source Terminal. This pin can be an input or an output.
12	10	FF	Fault Flag Digital Output. This pin has a high output when the device is in normal operation or a low when
10	11	V	a fault condition occurs on any of the Sx inputs.
13		V <sub>DD</sub>	Most Positive Power Supply Potential.
14	12	S2	Overvoltage Protected Source Terminal. This pin can be an input or an output.
15	13	D2	Overvoltage Protected Drain Terminal. This pin can be an input or an output.
16	14	IN2	Logic Control Input.
	EP	Exposed Pad	The exposed pad is internally connected. For increased reliability of the solder joints and maximum thermal capability, it is recommended that the pad be connected to the lowest supply voltage, V <sub>SS</sub> .

#### Table 8. ADG5412BF Truth Table

INx	Switch Condition (S1 to S4)
1	On
0	Off

#### Table 9. ADG5413BF Truth Table

	Switch Condition		
INx	S1, S4	S2, S3	
0	Off	On	
1	On	Off	

## **TYPICAL PERFORMANCE CHARACTERISTICS**











Figure 7. Row as a Function of Vs, VD (36 V Single-Supply)







Figure 9.  $R_{ON}$  as a Function of  $V_{S}$ ,  $V_D$  for Different Temperatures, ±20 V Dual-Supply



Figure 10.  $R_{ON}$  as a Function of  $V_{s,V_D}$  for Different Temperatures, 12 V Single-Supply

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## **Data Sheet**



Figure 11.  $R_{ON}$  as a Function of  $V_{S,V_D}$  for Different Temperatures, 36 V Single-Supply



Figure 12. Leakage Current vs. Temperature, ±15 V Dual-Supply



Figure 13. Leakage Current vs. Temperature, ±20 V Dual-Supply



Figure 14. Leakage Current vs. Temperature, 12 V Single-Supply







±15 V Dual-Supply



Figure 19. Overvoltage Drain Leakage Current vs. Temperature, 36 V Single-Supply











Figure 22. Charge Injection vs. Source Voltage (Vs), Single-Supply



Figure 23. Charge Injection vs. Source Voltage (V<sub>5</sub>), Dual-Supply







Figure 25. THD + N vs. Frequency,  $\pm 15$  V Dual-Supply











Figure 29. Drain Output Response to Positive Overvoltage



Figure 30. Drain Output Response to Negative Overvoltage



# \_\_\_\_\_

# ADG5412BF/ADG5413BF













Figure 36. Channel-to-Channel Crosstalk



Figure 37. Switch Overvoltage Leakage



Figure 38. Switch Unpowered Leakage





Figure 40. THD + N







Figure 46. Break-Before-Make Time Delay, t<sub>D</sub>







## TERMINOLOGY

#### Idd

IDD represents the positive supply current.

#### Iss

Iss represents the negative supply current.

#### VD, Vs

 $V_{\rm D}$  and  $V_{\rm S}$  represent the analog voltage on the Dx pins and the Sx pins, respectively.

#### Ron

 $R_{\mbox{\scriptsize ON}}$  represents the ohmic resistance between the Dx pins and the Sx pins.

#### $\Delta R_{ON}$

 $\Delta R_{\rm ON}$  represents the difference between the  $R_{\rm ON}$  of any two channels.

#### R<sub>FLAT(ON)</sub>

 $R_{FLAT(ON)}$  is the flatness that is defined as the difference between the maximum and minimum value of on resistance measured over the specified analog signal range.

#### Is (Off)

 $I_{\text{S}}\left(\text{Off}\right)$  is the source leakage current with the switch off.

#### I<sub>D</sub> (Off)

 $I_{\rm D}$  (Off) is the drain leakage current with the switch off.

#### $I_D$ (On), $I_S$ (On)

 $I_{\rm D}$  (On) and  $I_{\rm S}$  (On) represent the channel leakage currents with the switch on.

#### VINL

 $V_{\ensuremath{\text{INL}}}$  is the maximum input voltage for Logic 0.

#### VINH

 $V_{\mbox{\scriptsize INH}}$  is the minimum input voltage for Logic 1.

#### IINL, IINH

 $I_{\rm INL}$  and  $I_{\rm INH}$  represent the low and high input currents of the digital inputs.

#### C<sub>D</sub> (Off)

 $C_D$  (Off) represents the off switch drain capacitance, which is measured with reference to ground.

#### Cs (Off)

 $C_{s}$  (Off) represents the off switch source capacitance, which is measured with reference to ground.

#### $C_D$ (On), $C_S$ (On)

 $C_{\text{D}}$  (On) and  $C_{\text{s}}$  (On) represent on switch capacitances, which are measured with reference to ground.

#### Cin

 $C_{\mbox{\scriptsize IN}}$  is the digital input capacitance.

#### ton

 $t_{\rm ON}$  represents the delay between applying the digital control input and the output switching on (see Figure 47).

## ADG5412BF/ADG5413BF

#### toff

t<sub>OFF</sub> represents the delay between applying the digital control input and the output switching off (see Figure 47).

#### t<sub>D</sub>

 $t_{\rm D}$  represents the off time measured between the 90% point of both switches when switching from one address state to another.

#### **t**<sub>DIGRESP</sub>

 $t_{\text{DIGRESP}}$  is the time required for the FF pin to go low (0.3 V), measured with respect to voltage on the source pin exceeding the supply voltage by 0.5 V.

#### **t**digrec

 $t_{\text{DIGREC}}$  is the time required for the FF pin to return high (3 V), measured with respect to voltage on the Sx pin falling below the supply voltage plus 0.5 V.

#### **t**response

 $t_{\text{RESPONSE}}$  represents the delay between the source voltage exceeding the supply voltage by 0.5 V and the drain voltage falling to 90% of the supply voltage.

#### trecovery

 $t_{\text{RECOVERY}}$  represents the delay between an overvoltage on the Sx pin falling below the supply voltage plus 0.5 V and the drain voltage rising from 0 V to 10% of the supply voltage.

#### Off Isolation

Off isolation is a measure of unwanted signal coupling through an off switch.

#### **Charge Injection**

Charge injection is a measure of the glitch impulse transferred from the digital input to the analog output during switching.

#### Channel-to-Channel Crosstalk

Crosstalk is a measure of unwanted signal that is coupled through from one channel to another as a result of parasitic capacitance.

#### -3 dB Bandwidth

Bandwidth is the frequency at which the output is attenuated by 3 dB.

#### **On Response**

On response is the frequency response of the on switch.

#### **Insertion Loss**

Insertion loss is the loss due to the on resistance of the switch.

#### Total Harmonic Distortion Plus Noise (THD + N)

THD + N is the ratio of the harmonic amplitude plus noise of the signal to the fundamental.

#### AC Power Supply Rejection Ratio (ACPSRR)

ACPSRR is the ratio of the amplitude of signal on the output to the amplitude of the modulation. ACPSRR is a measure of the ability of the device to avoid coupling noise and spurious signals that appear on the supply voltage pin to the output of the switch. The dc voltage on the device is modulated by a sine wave of 0.62 V p-p.

#### VT

 $V_{\rm T}$  is the voltage threshold at which the overvoltage protection circuitry engages. See Figure 28.

### THEORY OF OPERATION switch architecture

Each channel of the ADG5412BF/ADG5413BF consists of a parallel pair of N-channel diffused metal-oxide semiconductor (NDMOS) and P-channel DMOS (PDMOS) transistors. This construction provides excellent performance across the signal range. The ADG5412BF/ADG5413BF channels operate as standard switches when input signals with a voltage between V<sub>SS</sub> and V<sub>DD</sub> are applied. For example, the on resistance is 10  $\Omega$  typically and the appropriate control pin, INx, controls the opening or closing of the switch.

Additional internal circuitry enables the switch to detect overvoltage inputs by comparing the voltage on the source or drain pin with  $V_{DD}$  and  $V_{SS}$ . A signal is considered overvoltage if it exceeds the supply voltages by the voltage threshold,  $V_T$ . The threshold voltage is typically 0.7 V, but can range from 0.8 V (when operating at -40°C) down to 0.6 V at +125°C. See Figure 28 to see the change in  $V_T$  with operating temperature.

The maximum voltage that can be applied to any switch input is +55 V or -55 V. When the device is powered using the single-supply of 25 V or greater, the maximum signal level reduces from -55 V to -40 V at  $V_{DD} = 40$  V to remain within the 80 V maximum rating. Construction of the process allows the channel to withstand 80 V across the switch when it is opened. These overvoltage limits apply whether the power supplies are present or not.



Figure 49. Switch Channel and Control Function

When an overvoltage condition is detected on either the source pin or drain pin, the switch is automatically opened regardless of the digital logic state, INx. The source and drain pins both become high impedance and ensure that no current flows through the switch. In Figure 29, the voltage on the drain pin can be seen to follow the voltage on the source pin until the switch has turned off completely and the drain voltage discharges through the load. The maximum voltage and the rate at which the output voltage discharges is dependent on the load at the pin. The ADG5412F/ ADG5413F are pin-compatible devices that are overvoltage protected on the source pin only, with ESD diodes on the drain pin that limit the maximum voltage while the switch is opening. During overvoltage conditions, the leakage current into and out of the switch pins is limited to tens of microamperes. This limit protects the switch and connected circuitry from over stresses as well as restricting the current drawn from the signal source. When an overvoltage event occurs, the channels undisturbed by the overvoltage input continue to operate normally without additional crosstalk.

#### ESD Performance

The ADG5412BF/ADG5413BF has an ESD rating of 3 kV for the human body model (HBM). ESD protection cells allow the voltage at the pins to exceed the supply voltage. See Figure 49 for a switch channel overview.

#### **Trench** Isolation

In the ADG5412BF and ADG5413BF, an insulating oxide layer (trench) is placed between the NDMOS and the PDMOS transistors of each switch. Parasitic junctions, which occur between the transistors in junction-isolated switches, are eliminated, and the result is a switch that is latch-up immune under all circumstances. These devices pass a JESD78D latch-up test of ±500 mA for 1 sec, which is the harshest test in the specification.



Figure 50. Trench Isolation

#### **FAULT PROTECTION**

When the voltages at the switch inputs exceed  $V_{DD}$  or  $V_{SS}$  by  $V_T$ , the switch turns off or, if the device is unpowered, the switch remains off. The switch input remains high impedance regardless of the digital input state or the load resistance, and the output acts as a virtual open circuit. Signal levels up to +55 V and -55 V are blocked in both the powered and unpowered condition as long as the 80 V limitation between the switch and supply pins is met.

#### **Power-On Protection**

The following three conditions must be satisfied for the switch to be in the on condition:

- $V_{DD}$  to  $V_{SS} \ge 8 V$
- Input signal is between  $V_{SS} V_T$  and  $V_{DD} + V_T$
- Digital logic control input, INx, is turned on

When the switch is turned on, signal levels up to the supply rails are passed.

The switch responds to an analog input that exceeds  $V_{\rm DD}$  or  $V_{SS}$  by a threshold voltage,  $V_{T}$ , by turning off. The absolute input voltage limits are -55 V and +55 V, while maintaining an 80 V limit between the source pin and the supply rails. The switch remains off until the voltage at the switch pin returns to between  $V_{\rm DD}$  and  $V_{SS}$ .

The fault response time ( $t_{RESPONSE}$ ) when powered by  $\pm 15 \text{ V}$  dual-supply is typically 460 ns, and the fault recovery time ( $t_{RECOVERY}$ ) is 720 ns. These vary with supply voltages and output load conditions.

Exceeding ±55 V on any switch input may damage the ESD protection circuitry on the device.

The maximum stress across the switch channel is 80 V; therefore, the user must pay close attention to this limit if using the device in a multiplexed configuration and one channel is on while another channel is in a fault condition.

For example, consider the case where the device is set up in a multiplexer configuration as shown in Figure 51.

- $V_{DD}/V_{SS} = \pm 22$  V, S1 = 22 V, all switches are on
- D1 is externally multiplexed with D2; therefore, D1 and D2 = 22 V
- S2 has a -55 V fault and S3 has a +55 V fault
- The voltage between S2 and D1 or between S2 and D2 = +22 V (-55 V) = +77 V
- The voltage between S3 and D3 = 55 V 0 V = 55 V

These calculations are all within device specifications: 55 V maximum fault on switch inputs and a maximum of 80 V across the off switch channel.



Figure 51. ADG5413BF in Multiplexer Configuration under Overvoltage Conditions

#### **Power-Off Protection**

When no power supplies are present, the switch remains in the off condition, and the switch inputs are high impedance. This state ensures that no current flows and prevents damage to the switch or downstream circuitry. The switch output is a virtual open circuit.

The switch remains off regardless of whether the  $V_{\rm DD}$  and  $V_{SS}$  supplies are 0 V or floating. A GND reference must always be present to ensure proper operation. Signal levels of up to  $\pm 55$  V are blocked in the unpowered condition.

#### **Digital Input Protection**

The ADG5412BF and the ADG5413BF can tolerate digital input signals being present on the device without power. When the device is unpowered, the switch is guaranteed to be in the off state, regardless of the state of the digital logic signals.

The digital inputs are protected against positive faults up to 44 V. The digital inputs do not offer protection against negative overvoltages. ESD protection diodes connected to GND are present on the digital inputs.

#### Overvoltage Interrupt Flag

The voltages on the switch inputs of the ADG5412BF and the ADG5413BF are continuously monitored and the state of the switch is indicated by an active low digital output pin, FF.

The voltage on the FF pin indicates if any of the switch input pins are experiencing a fault condition. The output of the FF pin is a nominal 3 V when all switch pins are within normal operating range. If any switch pin voltage exceeds the supply voltage by  $V_T$ , the FF output reduces to below 0.8 V.

## **APPLICATIONS INFORMATION**

The overvoltage protected family of switches and multiplexers provide a robust solution for instrumentation, industrial, aerospace, and other harsh environments where overvoltage signals can be present and the system must remain operational both during and after the overvoltage has occurred.

#### **POWER SUPPLY RAILS**

To guarantee correct operation of the device, 0.1  $\mu F$  decoupling capacitors are required.

The ADG5412BF and the ADG5413BF can operate with bipolar supplies between  $\pm 5$  V and  $\pm 22$  V. The supplies on VDD and VSS need not be symmetrical but the VDD to VSS range must not exceed 44 V. The ADG5412BF and the ADG5413BF can also operate with single supplies between 8 V and 44 V with VSS connected to GND.

These devices are fully specified at  $\pm 15$  V,  $\pm 20$  V,  $\pm 12$  V, and  $\pm 36$  V supply ranges.

#### POWER SUPPLY SEQUENCING PROTECTION

The switch channel remains open when the device is unpowered and signals from -55 V to +55 V can be applied without damaging the device. Only when the supplies are connected and a suitable digital control signal is placed on the INx pin does the switch channel close and then allow a signal to pass. Placing the ADG5412BF/ADG5413BF between external connectors and sensitive components offers protection in systems where a signal is presented to the switch pins before the supply voltages are available.

#### SIGNAL RANGE

The ADG5412BF/ADG5413BF switches have fault detection circuitry on their inputs that compares the voltage levels at the switch terminals with  $V_{DD}$  and  $V_{SS}$ , relative to ground. To protect downstream circuitry from overvoltages, supply the ADG5412BF/ADG5413BF by voltages that match the intended signal range. The low on-resistance switch allows signals up to the supply rails to be passed with very little distortion. A signal that exceeds the supply rail by the threshold voltage is then blocked. This offers protection to both the device and any downstream circuitry.

#### LOW IMPEDANCE CHANNEL PROTECTION

The ADG5412BF/ADG5413BF can be used as protective elements in signal chains that are sensitive to both channel impedance and overvoltage signals. Traditionally, series resistors are used to limit the current during an overvoltage condition to protect susceptible components. These series resistors affect the performance of the signal chain and reduce the precision that can be reached. A compromise must be reached on the value of the series resistance that is high enough to sufficiently protect sensitive components but low enough that the precision performance of the signal chain is not sacrificed. The ADG5412BF/ADG5413BF enable the designer to remove these resistors and retain the precision performance without compromising the protection of the circuit.

#### **HIGH VOLTAGE SURGE SUPPRESSION**

The ADG5412BF/ADG5413BF is not intended for use in very high voltage applications. The maximum operating voltage of the transistor is 80 V. In applications where the inputs are likely to be subject to overvoltages exceeding the breakdown voltage, use transient voltage suppressors (TVSs), or similar.

#### INTELLIGENT FAULT DETECTION

The ADG5412BF/ADG5413BF digital output pin, FF, can interface with a microprocessor or control system and be used as an interrupt flag. This feature provides real-time diagnostic information on the state of the device and the system to which it connects.

The control system can use the digital interrupt to start a variety of actions, such as

- Initiating investigation into the source of the overvoltage fault
- Shutting down critical systems in response to the overvoltage
- Data recorders marking data during these events as unreliable or out of specification

For systems that are sensitive during a start-up sequence, the active low operation of the flag allows the system to ensure that the ADG5412BF/ADG5413BF are powered on and that all input voltages are within normal operating range before initiating operation.

The FF pin is a weak pull-up, which allows the signals to be combined into a single interrupt for larger modules that contain multiple devices.

The recovery time,  $t_{\text{DIGREC}}$ , can be decreased from a typical 60  $\mu s$  to 600 ns by using a 1 k $\Omega$  pull-up resistor.

#### LARGE VOLTAGE, HIGH FREQUENCY SIGNALS

Figure 31 illustrates the voltage range and frequencies that the ADG5412BF/ADG5413BF can reliably convey. For signals that extend across the full signal range from  $V_{SS}$  to  $V_{DD}$ , keep the frequency below 3 MHz. If the required frequency is greater than 3 MHz, decrease the signal voltage appropriately to ensure signal integrity.

## **OUTLINE DIMENSIONS**



Figure 53. 16-Lead Lead Frame Chip Scale Package [LFCSP\_WQ] 4 mm × 4 mm Body, Very Very Thin Quad (CP-16-17) Dimensions shown in millimeters

#### **ORDERING GUIDE**

Model <sup>1</sup>	Temperature Range	Package Description	Package Option
ADG5412BFBRUZ	-40°C to +125°C	16-Lead Thin Shrink Small Outline Package [TSSOP]	RU-16
ADG5412BFBRUZ-RL7	-40°C to +125°C	16-Lead Thin Shrink Small Outline Package [TSSOP]	RU-16
ADG5412BFBCPZ-RL7	-40°C to +125°C	16-Lead Lead Frame Chip Scale Package [LFCSP_WQ]	CP-16-17
EVAL-ADG5412BFEBZ		Evaluation Board	
ADG5413BFBRUZ	-40°C to +125°C	16-Lead Thin Shrink Small Outline Package [TSSOP]	RU-16
ADG5413BFBRUZ-RL7	-40°C to +125°C	16-Lead Thin Shrink Small Outline Package [TSSOP]	RU-16
ADG5413BFBCPZ-RL7	-40°C to +125°C	16-Lead Lead Frame Chip Scale Package [LFCSP_WQ]	CP-16-17

<sup>1</sup> Z = RoHS Compliant Part.

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